

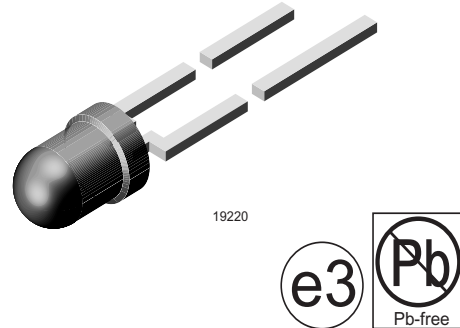
High Efficiency LED, \varnothing 3 mm Tinted Undiffused Package

Description

The TLH.42.. series was developed for standard applications like general indicating and lighting purposes.

It is housed in a 3 mm tinted clear plastic package. The wide viewing angle of these devices provides a high on-off contrast.

Several selection types with different luminous intensities are offered. All LEDs are categorized in luminous intensity groups. The green and yellow LEDs are categorized additionally in wavelength groups.



That allows users to assemble LEDs with uniform appearance.

Features

- Choice of five bright colors
- Standard T-1 package
- Small mechanical tolerances
- Suitable for DC and high peak current
- Wide viewing angle
- Luminous intensity categorized
- Yellow and green color categorized
- Lead-free device

Applications

- Status lights
- OFF / ON indicator
- Background illumination
- Readout lights
- Maintenance lights
- Legend light

Parts Table

| Part | Color, Luminous Intensity | Angle of Half Intensity ($\pm\phi$) | Technology |
|----------|-----------------------------|---------------------------------------|--------------|
| TLHR4200 | Red, $I_V > 4$ mcd | 22 ° | GaAsP on GaP |
| TLHR4201 | Red, $I_V > 6.3$ mcd | 22 ° | GaAsP on GaP |
| TLHR4205 | Red, $I_V > 10$ mcd | 22 ° | GaAsP on GaP |
| TLHO4200 | Soft orange, $I_V > 4$ mcd | 22 ° | GaAsP on GaP |
| TLHO4201 | Soft orange, $I_V > 10$ mcd | 22 ° | GaAsP on GaP |
| TLHY4200 | Yellow, $I_V > 4$ mcd | 22 ° | GaAsP on GaP |
| TLHY4201 | Yellow, $I_V > 6.3$ mcd | 22 ° | GaAsP on GaP |
| TLHY4205 | Yellow, $I_V > 10$ mcd | 22 ° | GaAsP on GaP |
| TLHG4200 | Green, $I_V > 6.3$ mcd | 22 ° | GaP on GaP |
| TLHG4201 | Green, $I_V > 10$ mcd | 22 ° | GaP on GaP |
| TLHG4205 | Green, $I_V > 16$ mcd | 22 ° | GaP on GaP |
| TLHP4200 | Pure green, $I_V > 2.5$ mcd | 22 ° | GaP on GaP |
| TLHP4201 | Pure green, $I_V > 6.3$ mcd | 22 ° | GaP on GaP |

Absolute Maximum Ratings

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

TLHR42.., TLHO42.., TLHY42.., TLHG42.., TLHP42..

| Parameter | Test condition | Symbol | Value | Unit |
|---|---|------------|---------------|--------------------|
| Reverse voltage | | V_R | 6 | V |
| DC Forward current | | I_F | 30 | mA |
| Surge forward current | $t_p \leq 10\text{ }\mu\text{s}$ | I_{FSM} | 1 | A |
| Power dissipation | $T_{amb} \leq 60\text{ }^{\circ}\text{C}$ | P_V | 100 | mW |
| Junction temperature | | T_j | 100 | $^{\circ}\text{C}$ |
| Operating temperature range | | T_{amb} | - 40 to + 100 | $^{\circ}\text{C}$ |
| Storage temperature range | | T_{stg} | - 55 to + 100 | $^{\circ}\text{C}$ |
| Soldering temperature | $t \leq 5\text{ s}$, 2 mm from body | T_{sd} | 260 | $^{\circ}\text{C}$ |
| Thermal resistance junction/ ambient | | R_{thJA} | 400 | K/W |

Optical and Electrical Characteristics

$T_{amb} = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Red

TLHR42..

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|----------------------------------|--------------------------------|----------|-------------|-----|----------|-----|------|
| Luminous intensity ¹⁾ | $I_F = 10\text{ mA}$ | TLHR4200 | I_V | 4 | 8 | | mcd |
| | | TLHR4201 | I_V | 6.3 | 10 | | mcd |
| | | TLHR4205 | I_V | 10 | 15 | | mcd |
| Dominant wavelength | $I_F = 10\text{ mA}$ | | λ_d | 612 | | 625 | nm |
| Peak wavelength | $I_F = 10\text{ mA}$ | | λ_p | | 635 | | nm |
| Angle of half intensity | $I_F = 10\text{ mA}$ | | φ | | ± 22 | | deg |
| Forward voltage | $I_F = 20\text{ mA}$ | | V_F | | 2 | 3 | V |
| Reverse voltage | $I_R = 10\text{ }\mu\text{A}$ | | V_R | 6 | 15 | | V |
| Junction capacitance | $V_R = 0$, $f = 1\text{ MHz}$ | | C_j | | 50 | | pF |

¹⁾ in one Packing Unit $I_{Vmin}/I_{Vmax} \leq 0.5$

Soft Orange

TLHO42..

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|----------------------------------|--------------------------------|----------|-------------|-----|----------|-----|---------------|
| Luminous intensity ¹⁾ | $I_F = 10\text{ mA}$ | TLHO4200 | I_V | 4 | 10 | | mcd |
| | | TLHO4201 | I_V | 10 | 18 | | mcd |
| Dominant wavelength | $I_F = 10\text{ mA}$ | | λ_d | 598 | | 611 | nm |
| Peak wavelength | $I_F = 10\text{ mA}$ | | λ_p | | 605 | | nm |
| Angle of half intensity | $I_F = 10\text{ mA}$ | | φ | | ± 22 | | deg |
| Forward voltage | $I_F = 20\text{ mA}$ | | V_F | | 2.4 | 3 | V |
| Reverse current | $V_R = 6\text{ V}$ | | I_R | | | 10 | μA |
| Junction capacitance | $V_R = 0$, $f = 1\text{ MHz}$ | | C_j | | 50 | | pF |

¹⁾ in one Packing Unit $I_{Vmin}/I_{Vmax} \leq 0.5$



Yellow

TLHY42..

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|----------------------------------|--------------------------------|----------|-------------|-----|----------|-----|------|
| Luminous intensity ¹⁾ | $I_F = 10 \text{ mA}$ | TLHY4200 | I_V | 4 | 10 | | mcd |
| | | TLHY4201 | I_V | 6.3 | 15 | | mcd |
| | | TLHY4205 | I_V | 10 | 20 | | mcd |
| Dominant wavelength | $I_F = 10 \text{ mA}$ | | λ_d | 581 | | 594 | nm |
| Peak wavelength | $I_F = 10 \text{ mA}$ | | λ_p | | 585 | | nm |
| Angle of half intensity | $I_F = 10 \text{ mA}$ | | ϕ | | ± 22 | | deg |
| Forward voltage | $I_F = 20 \text{ mA}$ | | V_F | | 2.4 | 3 | V |
| Reverse voltage | $I_R = 10 \text{ }\mu\text{A}$ | | V_R | 6 | 15 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |

¹⁾ in one Packing Unit $I_{Vmin}/I_{Vmax} \leq 0.5$

Green

TLHG42..

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|----------------------------------|--------------------------------|----------|-------------|-----|----------|-----|------|
| Luminous intensity ¹⁾ | $I_F = 10 \text{ mA}$ | TLHG4200 | I_V | 6.3 | 10 | | mcd |
| | | TLHG4201 | I_V | 10 | 15 | | mcd |
| | | TLHG4205 | I_V | 16 | 20 | | mcd |
| Dominant wavelength | $I_F = 10 \text{ mA}$ | | λ_d | 562 | | 575 | nm |
| Peak wavelength | $I_F = 10 \text{ mA}$ | | λ_p | | 565 | | nm |
| Angle of half intensity | $I_F = 10 \text{ mA}$ | | ϕ | | ± 22 | | deg |
| Forward voltage | $I_F = 20 \text{ mA}$ | | V_F | | 2.4 | 3 | V |
| Reverse voltage | $I_R = 10 \text{ }\mu\text{A}$ | | V_R | 6 | 15 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |

¹⁾ in one Packing Unit $I_{Vmin}/I_{Vmax} \leq 0.5$

Pure green

TLHP42..

| Parameter | Test condition | Part | Symbol | Min | Typ. | Max | Unit |
|----------------------------------|--------------------------------|----------|-------------|-----|----------|-----|------|
| Luminous intensity ¹⁾ | $I_F = 10 \text{ mA}$ | TLHP4200 | I_V | 2.5 | 7 | | mcd |
| | | TLHP4201 | I_V | 6.3 | | 20 | mcd |
| Dominant wavelength | $I_F = 10 \text{ mA}$ | | λ_d | 555 | | 565 | nm |
| Peak wavelength | $I_F = 10 \text{ mA}$ | | λ_p | | 555 | | nm |
| Angle of half intensity | $I_F = 10 \text{ mA}$ | | ϕ | | ± 22 | | deg |
| Forward voltage | $I_F = 20 \text{ mA}$ | | V_F | | 2.4 | 3 | V |
| Reverse voltage | $I_R = 10 \text{ }\mu\text{A}$ | | V_R | 6 | 15 | | V |
| Junction capacitance | $V_R = 0, f = 1 \text{ MHz}$ | | C_j | | 50 | | pF |

¹⁾ in one Packing Unit $I_{Vmin}/I_{Vmax} \leq 0.5$

Typical Characteristics ($T_{amb} = 25\text{ }^{\circ}\text{C}$ unless otherwise specified)

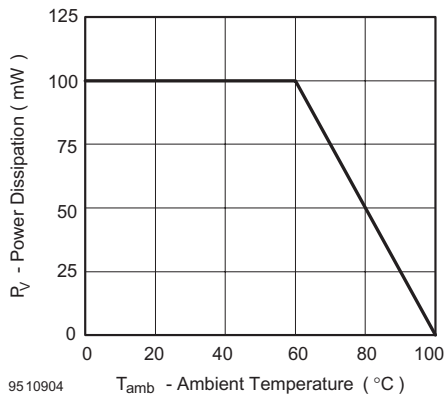


Figure 1. Power Dissipation vs. Ambient Temperature

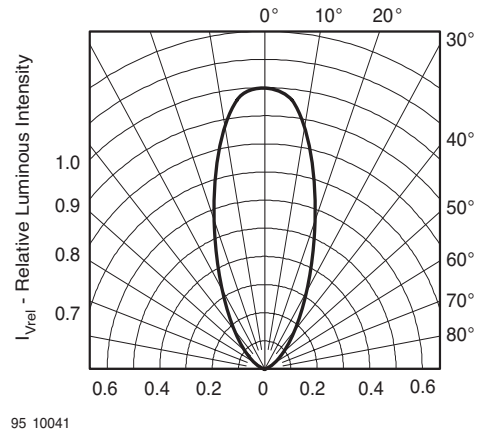


Figure 4. Rel. Luminous Intensity vs. Angular Displacement

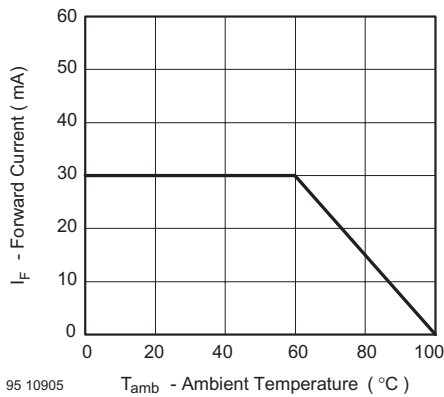


Figure 2. Forward Current vs. Ambient Temperature for InGaN

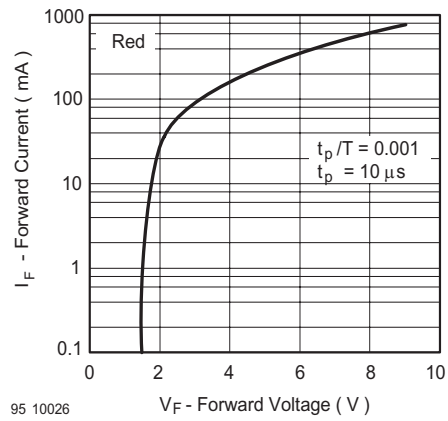


Figure 5. Forward Current vs. Forward Voltage

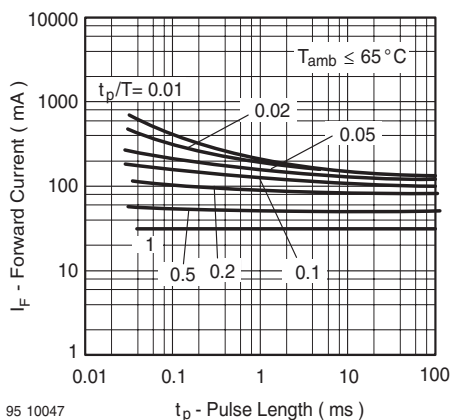


Figure 3. Forward Current vs. Pulse Length

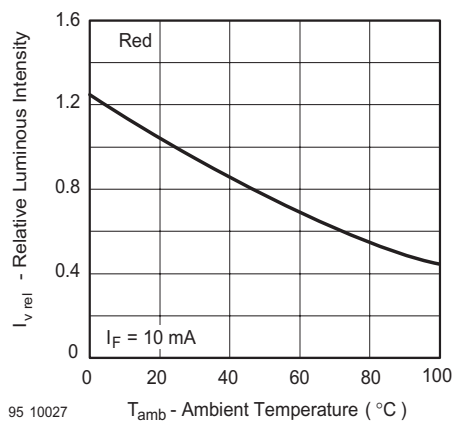


Figure 6. Rel. Luminous Intensity vs. Ambient Temperature

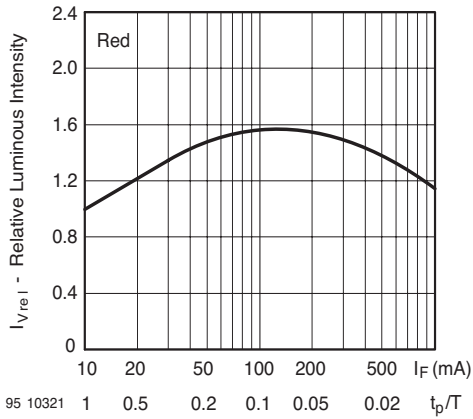


Figure 7. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

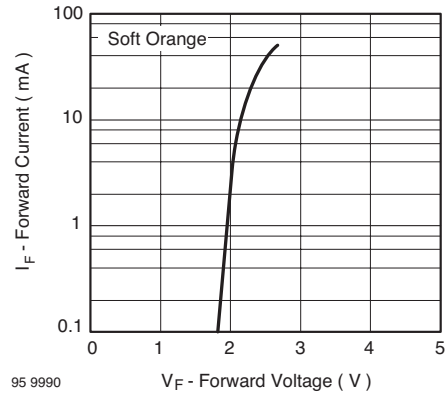


Figure 10. Forward Current vs. Forward Voltage

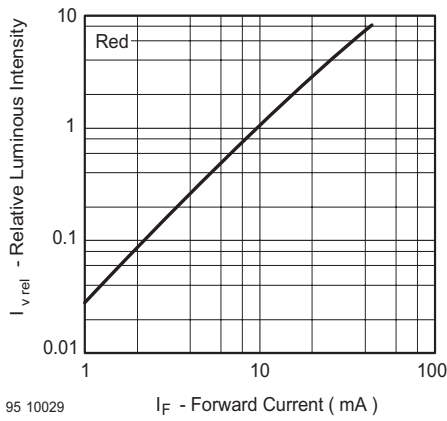


Figure 8. Relative Luminous Intensity vs. Forward Current

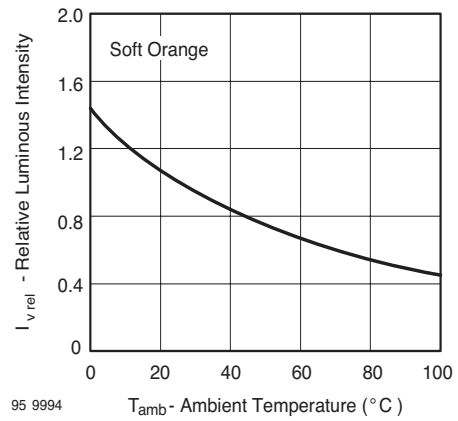


Figure 11. Rel. Luminous Intensity vs. Ambient Temperature

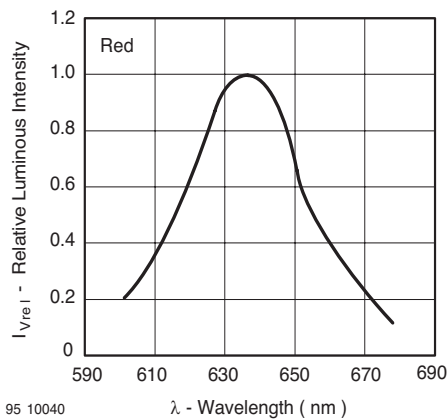


Figure 9. Relative Intensity vs. Wavelength

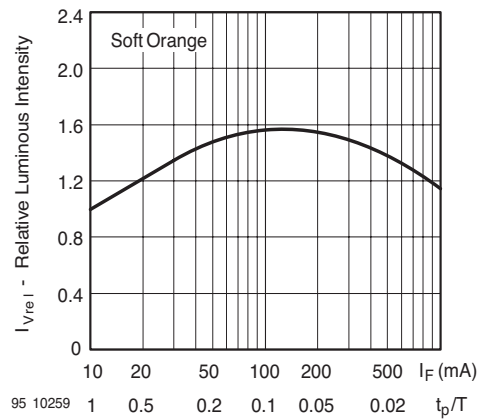


Figure 12. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

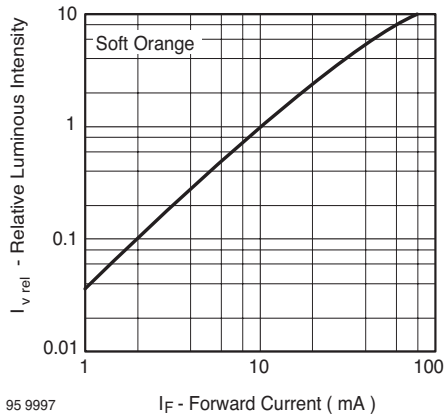


Figure 13. Relative Luminous Intensity vs. Forward Current

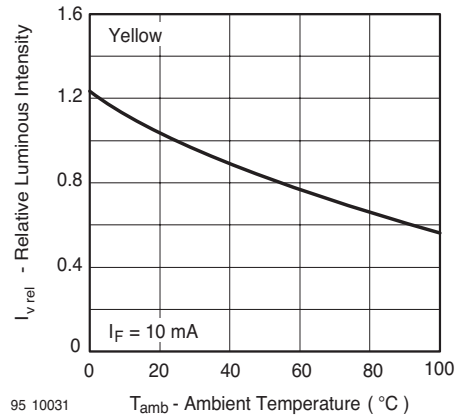


Figure 16. Rel. Luminous Intensity vs. Ambient Temperature

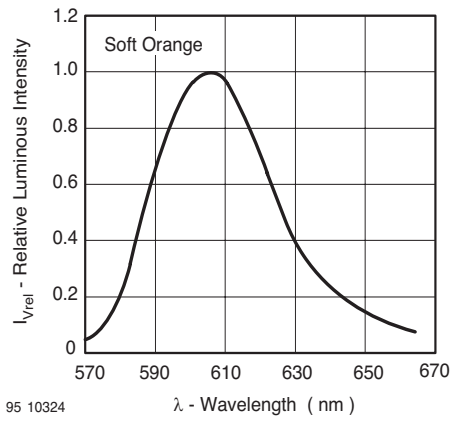


Figure 14. Relative Intensity vs. Wavelength

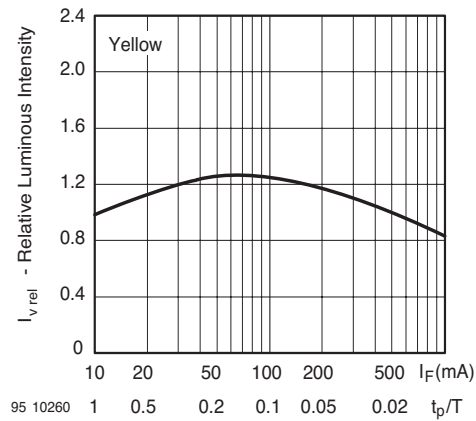


Figure 17. Rel. Lumin. Intensity vs. Forw. Current/Duty Cycle

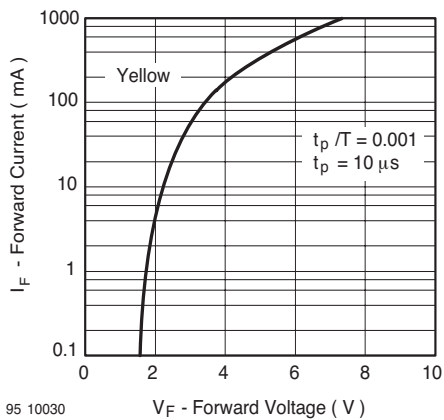


Figure 15. Forward Current vs. Forward Voltage

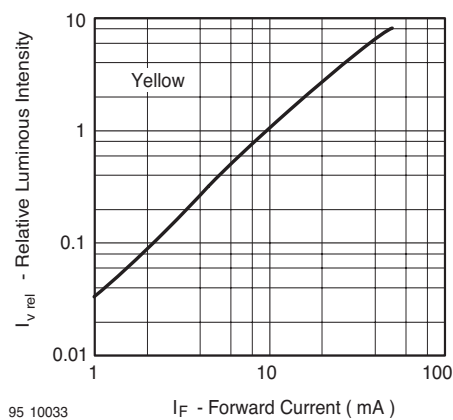


Figure 18. Relative Luminous Intensity vs. Forward Current

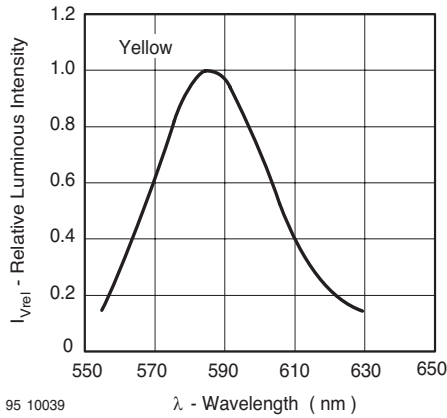


Figure 19. Relative Intensity vs. Wavelength

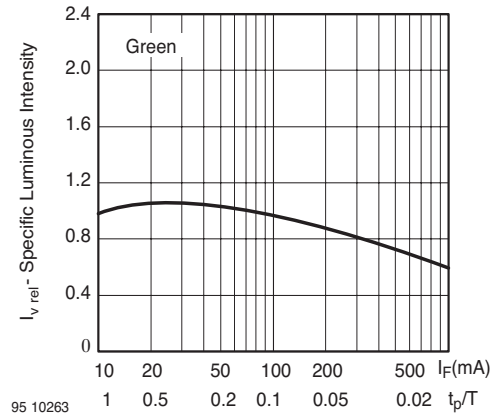


Figure 22. Specific Luminous Intensity vs. Forward Current

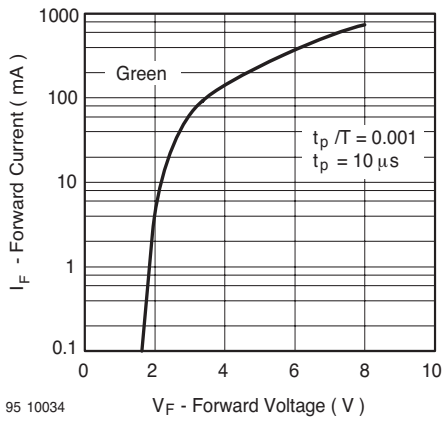


Figure 20. Forward Current vs. Forward Voltage

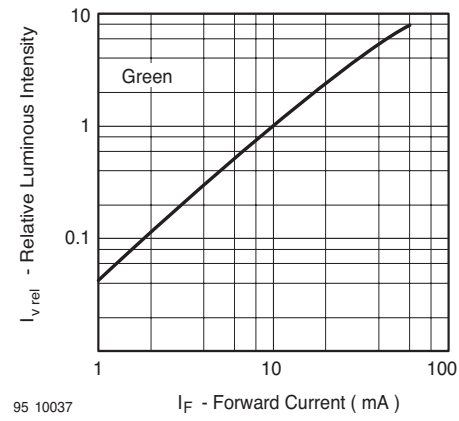


Figure 23. Relative Luminous Intensity vs. Forward Current

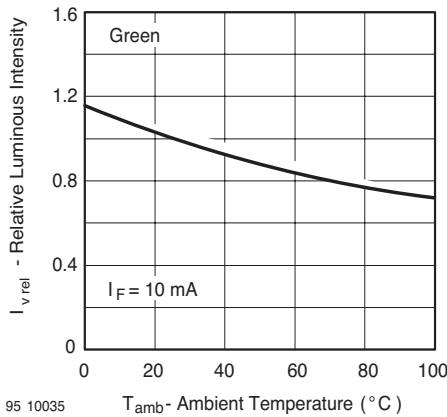


Figure 21. Rel. Luminous Intensity vs. Ambient Temperature

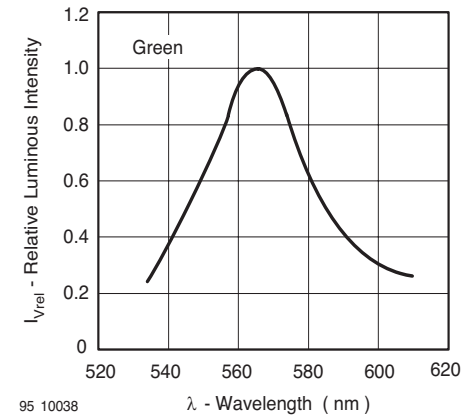


Figure 24. Relative Intensity vs. Wavelength

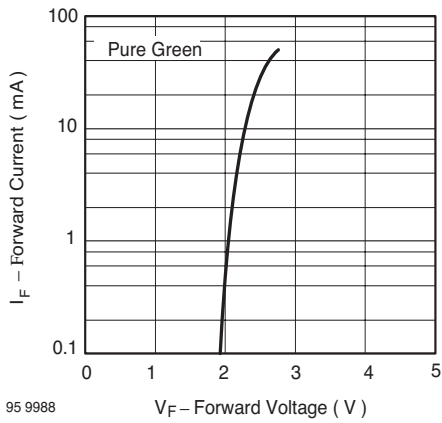


Figure 25. Forward Current vs. Forward Voltage

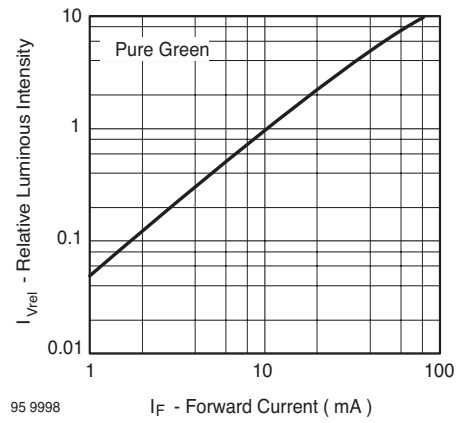


Figure 28. Relative Luminous Intensity vs. Forward Current

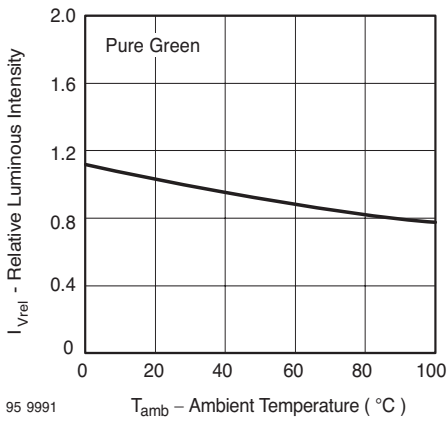


Figure 26. Rel. Luminous Intensity vs. Ambient Temperature

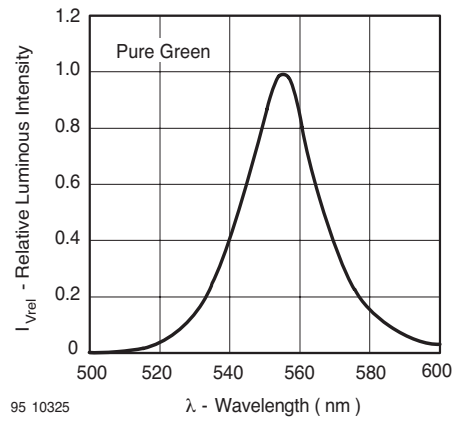


Figure 29. Relative Intensity vs. Wavelength

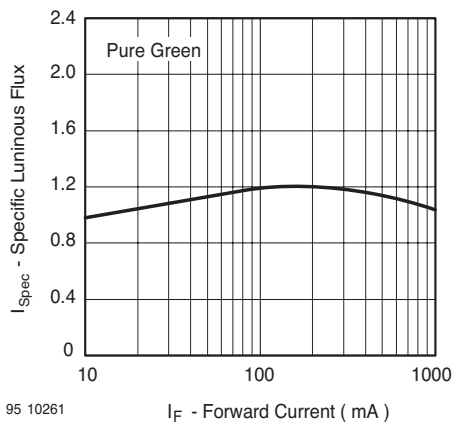
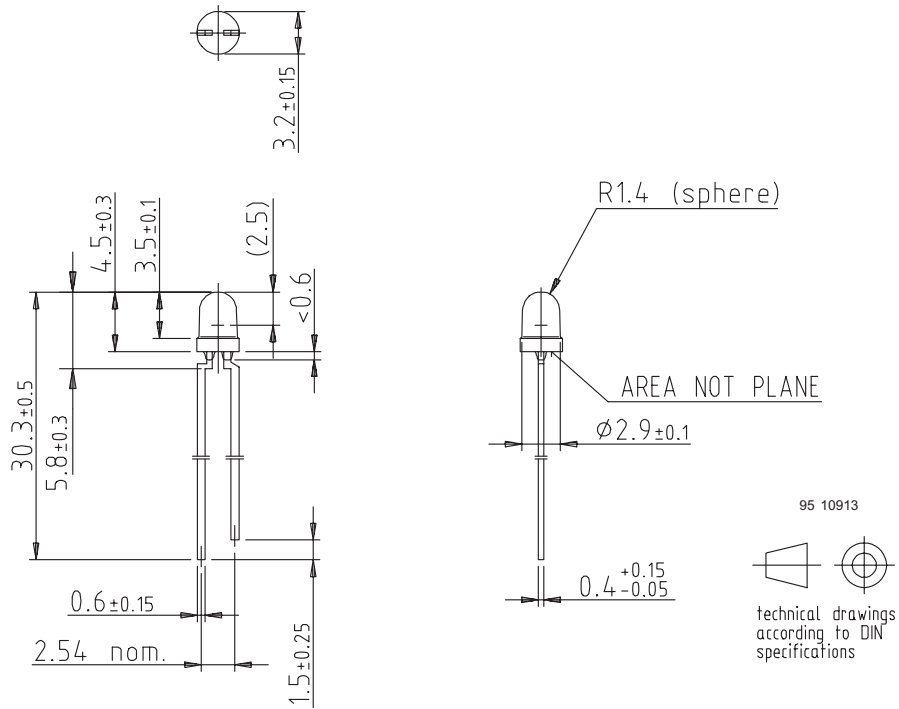


Figure 27. Specific Luminous Intensity vs. Forward Current



Package Dimensions in mm



Vishay Semiconductors

Ozone Depleting Substances Policy Statement

It is the policy of **Vishay Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

**We reserve the right to make changes to improve technical design
and may do so without further notice.**

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423

Компания «Life Electronics» занимается поставками электронных компонентов импортного и отечественного производства от производителей и со складов крупных дистрибьюторов Европы, Америки и Азии.

С конца 2013 года компания активно расширяет линейку поставок компонентов по направлению коаксиальный кабель, кварцевые генераторы и конденсаторы (керамические, пленочные, электролитические), за счёт заключения дистрибьюторских договоров

Мы предлагаем:

- Конкуренеспособные цены и скидки постоянным клиентам.
- Специальные условия для постоянных клиентов.
- Подбор аналогов.
- Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.
- Приемлемые сроки поставки, возможна ускоренная поставка.
- Доставку товара в любую точку России и стран СНГ.
- Комплексную поставку.
- Работу по проектам и поставку образцов.
- Формирование склада под заказчика.
- Сертификаты соответствия на поставляемую продукцию (по желанию клиента).
- Тестирование поставляемой продукции.
- Поставку компонентов, требующих военную и космическую приемку.
- Входной контроль качества.
- Наличие сертификата ISO.

В составе нашей компании организован Конструкторский отдел, призванный помогать разработчикам, и инженерам.

Конструкторский отдел помогает осуществить:

- Регистрацию проекта у производителя компонентов.
- Техническую поддержку проекта.
- Защиту от снятия компонента с производства.
- Оценку стоимости проекта по компонентам.
- Изготовление тестовой платы монтаж и пусконаладочные работы.



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